

# COMPTES RENDUS PHYSIQUE

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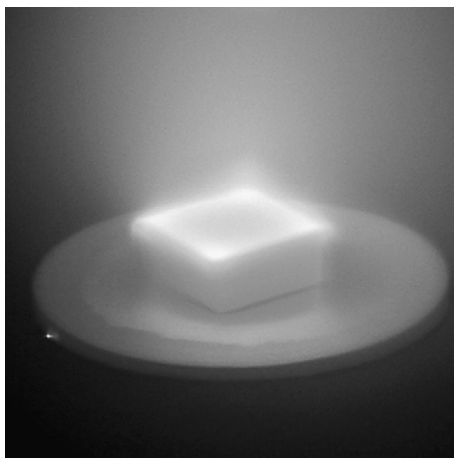


Image of a diamond single crystal during growth by plasma-assisted chemical vapour deposition.  
Image credit: Laboratoire des sciences des procédés et des matériaux, Villetaneuse, France.

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